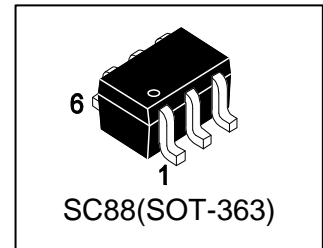


LMUN5311DW1T1G

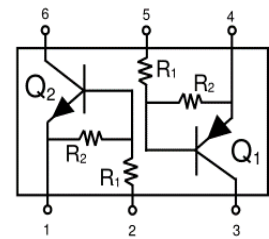
S-LMUN5311DW1T1G

Dual Bias Resistor Transistors
NPN and PNP Silicon Surface Mount Transistors
with Monolithic Bias Resistor Network



1. FEATURES

- Simplifies circuit design
- Reduces board space.
- Reduces Component Count
- We declare that the material of product compliance with RoHS requirements and Halogen Free.
- S- prefix for automotive and other applications requiring unique site and control change requirements; AEC-Q101 qualified and PPAP capable.



2. DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1(K)	R2(K)	Vin(V)(PNP)	Vin(V)(NPN)	Shipping
LMUN5311DW1T1G	11	10	10	-40~+10	-10~+40	3000/Tape&Reel
LMUN5311DW1T3G	11	10	10	-40~+10	-10~+40	10000/Tape&Reel

3. MAXIMUM RATINGS(Ta = 25°C)

Parameter	Symbol	Limits	Unit
Collector–Emitter Voltage	VCEO	50	V
Collector–Base Voltage	VCBO	50	V
Collector Current — Continuous	IC	100	mA

4. THERMAL CHARACTERISTICS

Parameter (One Junction Heated)	Symbol	Limits	Unit
Total Device Dissipation, (Note 1) @ TA = 25°C	PD	187	mW
Derate above 25°C		1.5	mW/°C
Thermal Resistance, Junction–to–Ambient(Note 1)	RθJA	670	°C/W
Parameter (Both Junctions Heated)	Symbol	Limits	Unit
Total Device Dissipation, (Note 1) @ TA = 25°C	PD	250	mW
Derate above 25°C		2	mW/°C
Thermal Resistance, Junction–to–Ambient(Note 1)	RθJA	493	°C/W
Thermal Resistance, Junction–to–Lead(Note 1)	RθJL	188	°C/W
Junction and Storage temperature	TJ,Tstg	-55~+150	°C

1. FR-4 @ Minimum Pad

5. ELECTRICAL CHARACTERISTICS (Ta= 25°C)

OFF CHARACTERISTICS

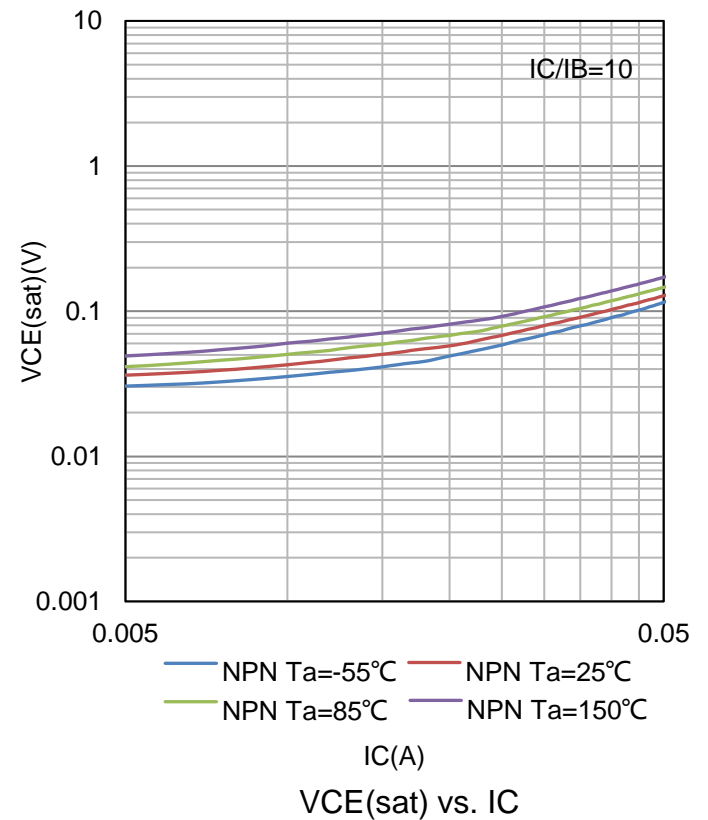
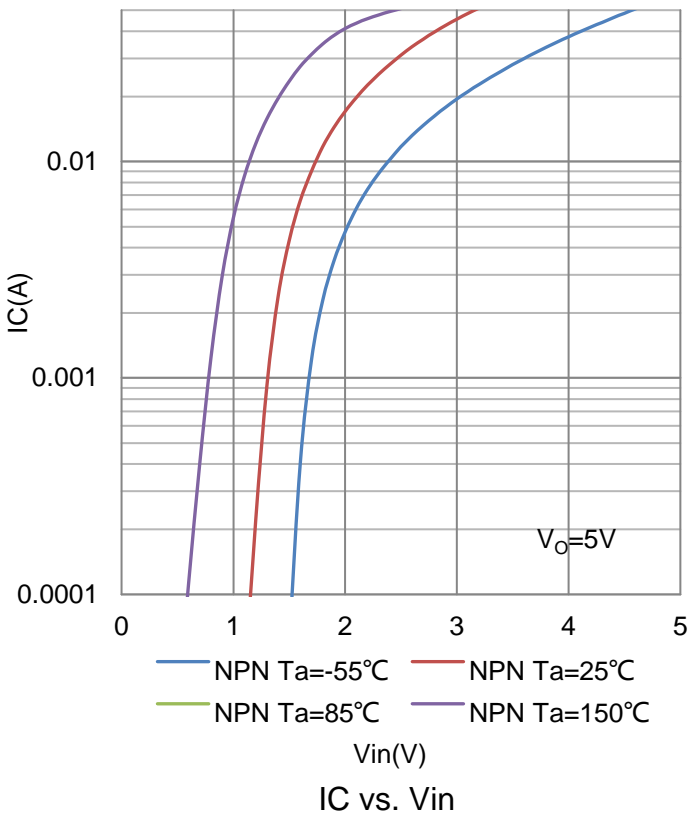
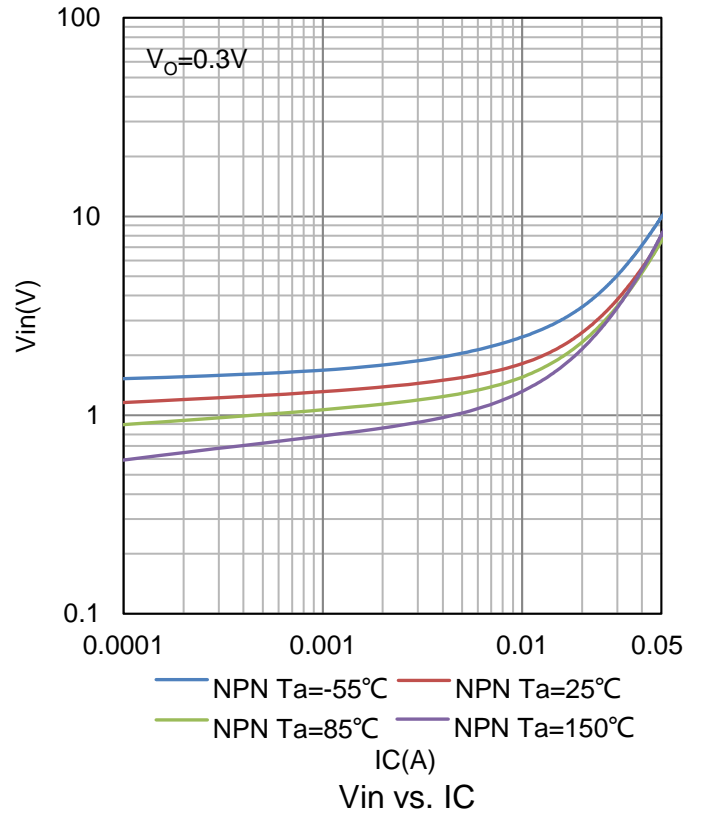
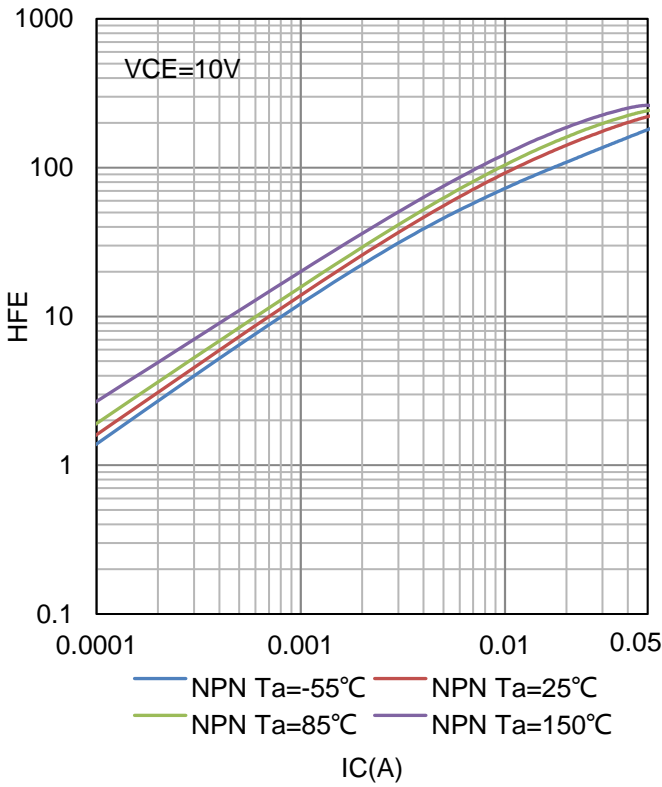
Characteristic	Symbol	Min.	Typ.	Max.	Unit
Collector–Emitter Breakdown Voltage (IC = 2.0 mA, IB = 0)	VBR(CEO)	50	-	-	V
Collector–Base Breakdown Voltage (IC = 10 μA, IE = 0)	VBR(CBO)	50	-	-	V
Collector-Base Cutoff Current (VCB = 50 V, IE = 0)	ICBO	-	-	100	nA
Collector-Emitter Cutoff Current (VCE = 50 V, IB = 0)	ICEO	-	-	500	nA
Emitter-Base Cutoff Current (VEB = 6.0 V, IC = 0)	IEBO	-	-	0.5	mA

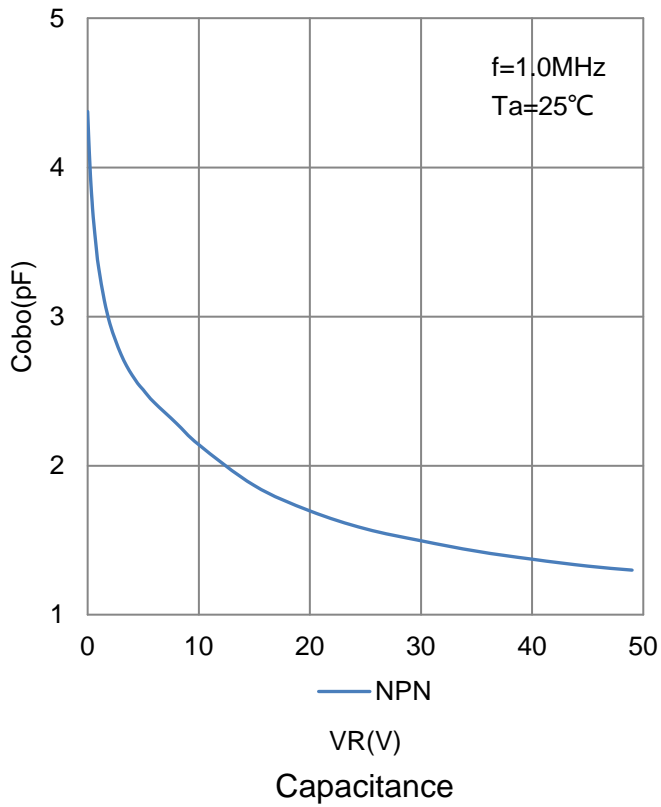
ON CHARACTERISTICS (Note 2.)

DC Current Gain (IC = 5.0 mA, VCE = 10 V)	HFE	35	60	-	
Collector–Emitter Saturation Voltage (IC = 10 mA, IB = 0.3 mA)	VCE(sat)	-	-	0.25	V
On-State Input Voltage (VCE=0.3V, IC=10mA)(NPN) (VCE=-0.3V, IC=-10mA)(PNP)	VI(on)	3 -3	- -	- -	V
Off-State Input Voltage (VCE=5V, IC=0.1mA)(NPN) (VCE=-5V, IC=-0.1mA)(PNP)	VI(off)	- -	- -	0.5 -0.5	V
Output Voltage (on) (VCC = 5.0 V, VB = 2.5 V, RL = 1.0KΩ)	VOL	-	-	0.2	V
Output Voltage (on) (VCC = 5.0 V, VB = 0.5 V, RL = 1.0KΩ)	VOH	4.9	-	-	V
Current–Gain — Bandwidth Product (VCE = 10V, IE = -5mA, f=100MHz)	fT	-	250	-	MHz
Input Resistor	R1	7	10	13	KΩ
Resistor Ratio	R1/R2	0.8	1	1.2	

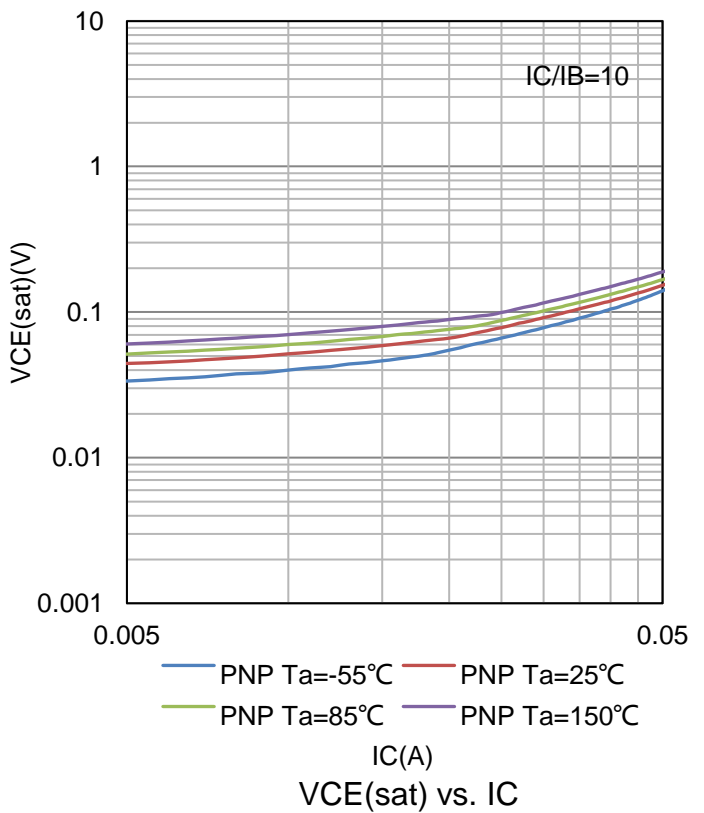
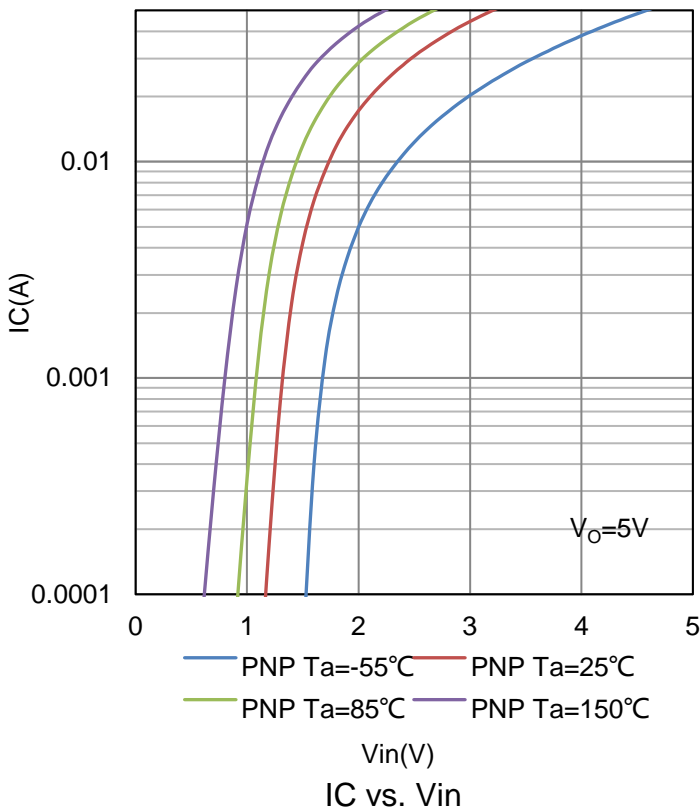
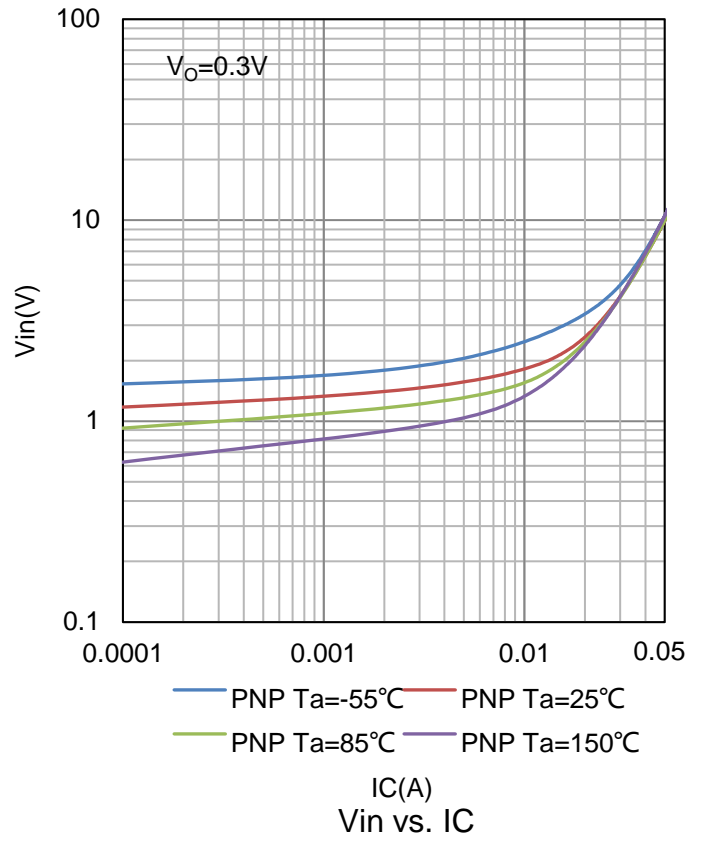
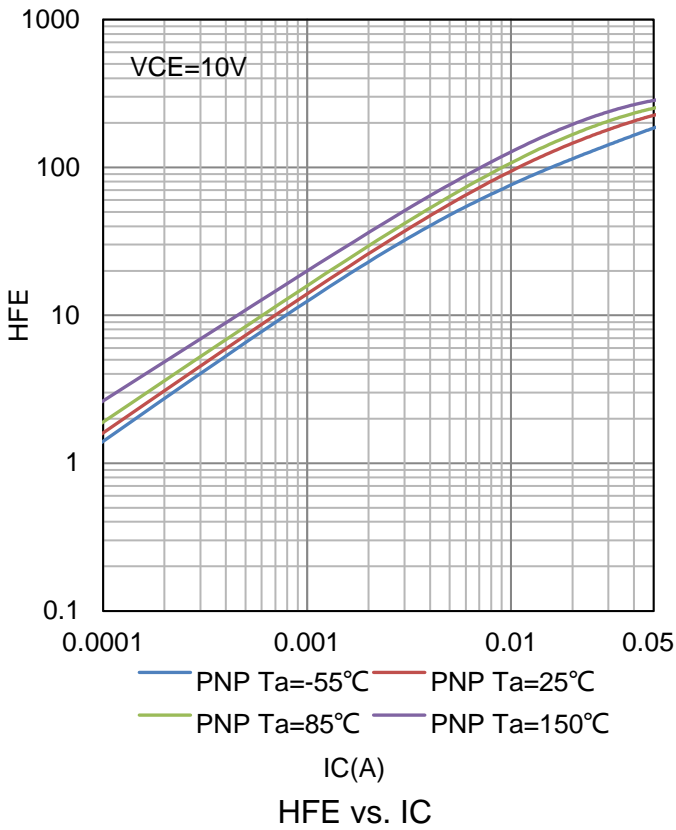
2. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 2.0%

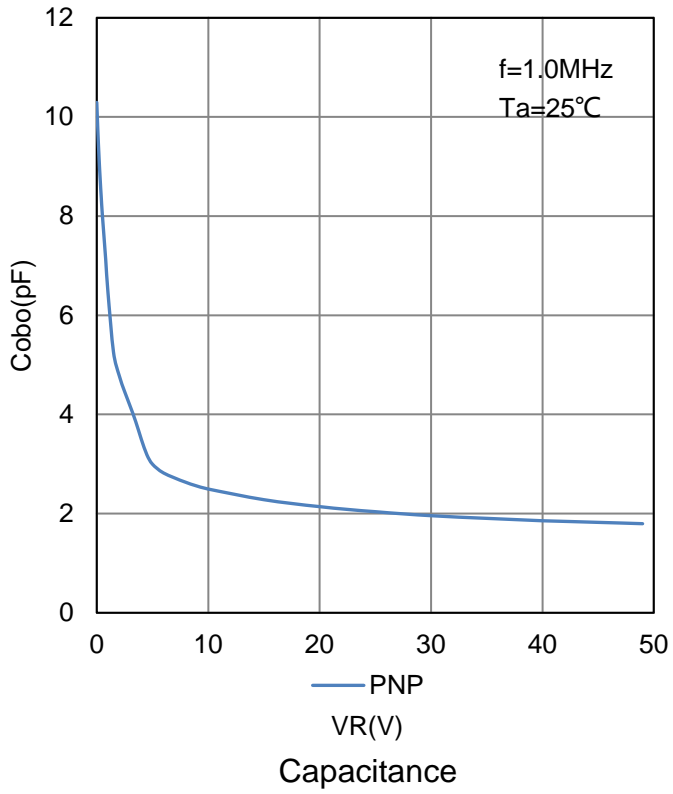
6. ELECTRICAL CHARACTERISTICS CURVES



6. ELECTRICAL CHARACTERISTICS CURVES(Con.)

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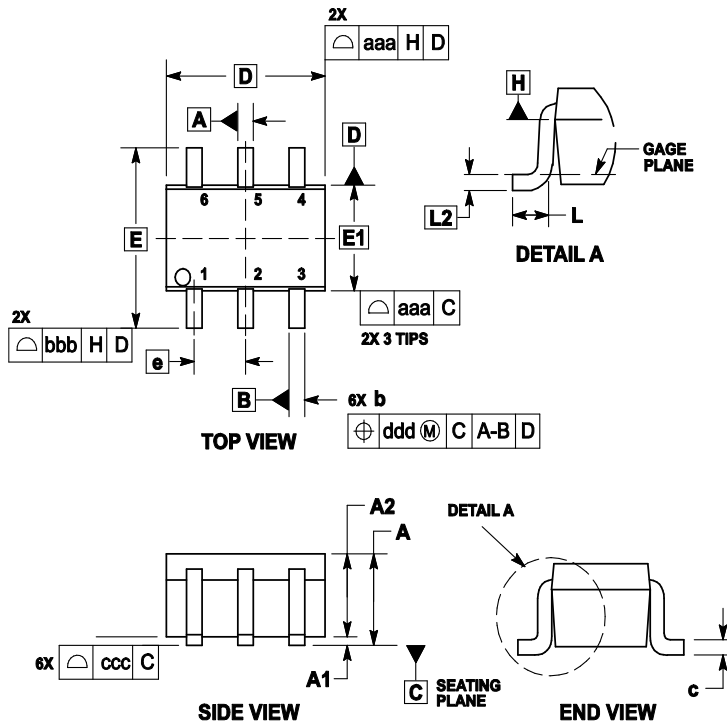


6. ELECTRICAL CHARACTERISTICS CURVES(Con.)

7. OUTLINE AND DIMENSIONS

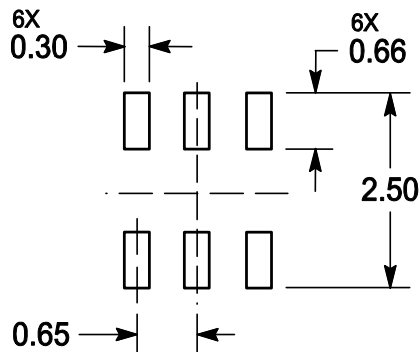
Notes:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS.



DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	---	---	1.10	---	---	0.043
A1	0.00	---	0.10	0	---	0.004
A2	0.70	0.90	1.00	0.027	0.035	0.039
b	0.15	0.20	0.25	0.006	0.008	0.01
C	0.08	0.15	0.22	0.003	0.006	0.009
D	1.80	2.00	2.20	0.07	0.078	0.086
E	2.00	2.10	2.20	0.078	0.082	0.086
E1	1.15	1.25	1.35	0.045	0.049	0.053
e	0.65 BSC			0.026 BSC		
L	0.26	0.36	0.46	0.010	0.014	0.018
L2	0.15 BSC			0.006 BSC		
aaa	0.15			0.01		
bbb	0.30			0.01		
ccc	0.10			0.00		
ddd	0.10			0.00		

8. SOLDERING FOOTPRINT



DISCLAIMER

- Curve guarantee in the specification. The curve of test items with electric parameter is used as quality guarantee. The curve of test items without electric parameter is used as reference only.
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